



BYT79X-600

Rectifier diode ultrafast

27 May 2015

Product data sheet

1. General description

Ultrafast power diode in a SOD113 (2-lead TO-220F) plastic package

2. Features and benefits

- Fast switching
- Low thermal resistance
- Soft recovery characteristic
- Low forward voltage drop
- Low switching loss
- High thermal cycling performance

3. Application information

- Output rectifiers in high frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V _{RRM}	repetitive peak reverse voltage			-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _h ≤ 49 °C; Square-wave; Fig. 1 ; Fig. 2		-	-	15	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _h ≤ 49 °C; Square-wave		-	-	30	A
I _{FSM}	non-repetitive peak forward current	t _p = 8.3 ms; T _{j(init)} = 25 °C; sinusoidal waveform		-	-	143	A
		t _p = 10 ms; T _{j(init)} = 25 °C; sinusoidal waveform		-	-	130	A
Static characteristics							
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; Fig. 4		-	1.16	1.38	V
		I _F = 15 A; T _j = 150 °C		-	1.01	1.2	V



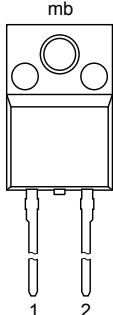
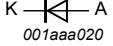
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Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Dynamic characteristics						
t_{rr}	reverse recovery time	$I_F = 1\text{ A}$; $V_R \geq 30\text{ V}$; $dI_F/dt = 100\text{ A}/\mu\text{s}$; $T_J = 25\text{ }^\circ\text{C}$; Fig. 5	-	50	60	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	 <p>TO-220F (SOD113)</p>	
2	A	anode		
mb	n.c.	mounting base; isolated		

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BYT79X-600	TO-220F	plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 "full pack"	SOD113

7. Limiting values

Table 4. Limiting values
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	Square-wave; $\delta = 1.0$	-	600	V
I _{F(AV)}	average forward current	$\delta = 0.5$; $T_h \leq 49\text{ }^{\circ}\text{C}$; Square-wave; Fig. 1 ; Fig. 2	-	15	A
I _{FRM}	repetitive peak forward current	$\delta = 0.5$; $t_p = 25\text{ }\mu\text{s}$; $T_h \leq 49\text{ }^{\circ}\text{C}$; Square-wave	-	30	A
I _{FSM}	non-repetitive peak forward current	$t_p = 8.3\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$; sinusoidal waveform	-	143	A
		$t_p = 10\text{ ms}$; $T_{j(\text{init})} = 25\text{ }^{\circ}\text{C}$; sinusoidal waveform	-	130	A
T _{stg}	storage temperature		-55	150	$^{\circ}\text{C}$
T _j	junction temperature		-	150	$^{\circ}\text{C}$

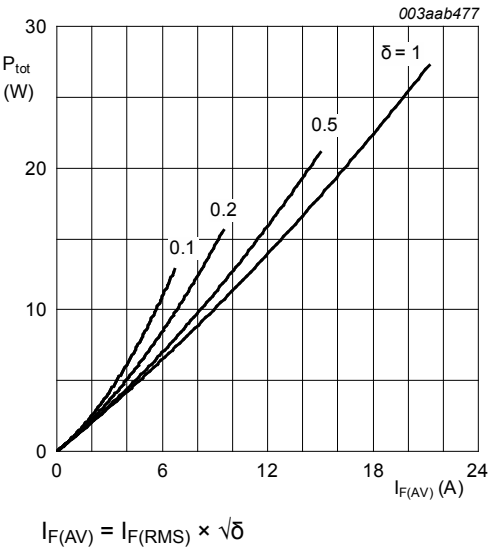


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

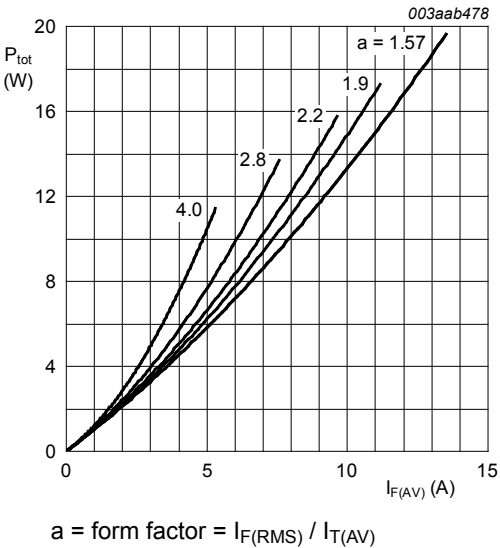


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	with heatsink compound; Fig. 3	-	-	4.8	K/W
		without heatsink compound	-	-	5.9	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W

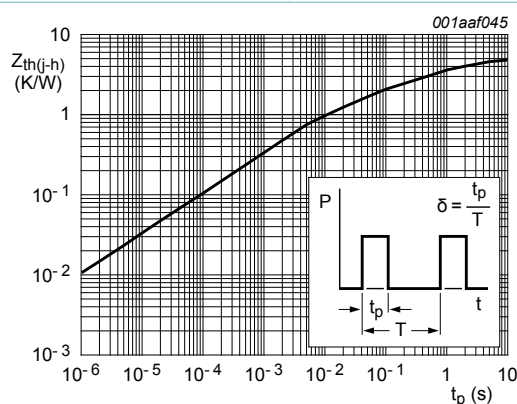


Fig. 3. Transient thermal impedance from junction to heatsink as a function of pulse width

9. Isolation characteristics

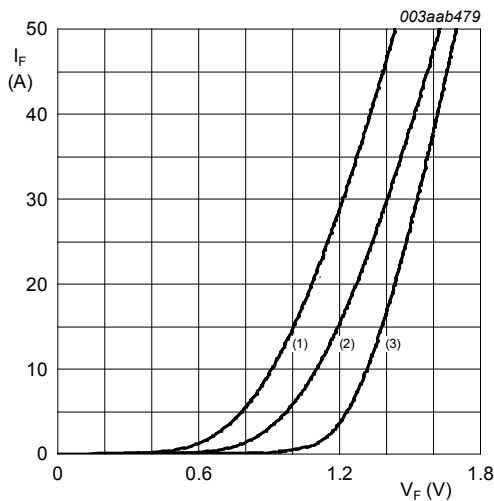
Table 6. Isolation characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{isol(RMS)}$	RMS isolation voltage	50 Hz ≤ f ≤ 60 Hz; RH ≤ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
C_{isol}	isolation capacitance	from cathode to external heatsink	-	10	-	pF

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V _F	forward voltage	I _F = 15 A; T _j = 25 °C; Fig. 4		-	1.16	1.38	V
		I _F = 15 A; T _j = 150 °C		-	1.01	1.2	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C		-	5	50	μA
		V _R = 600 V; T _j = 100 °C		-	0.2	0.8	mA
Dynamic characteristics							
Q _r	recovered charge	I _F = 2 A; V _R ≥ 30 V; dI _F /dt = 20 A/μs; Fig. 5		-	40	70	nC
t _{rr}	reverse recovery time	I _F = 1 A; V _R ≥ 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; Fig. 5		-	50	60	ns
I _{RM}	peak reverse recovery current	I _F = 10 A; V _R ≥ 30 V; dI _F /dt = 50 A/μs; T _j = 100 °C; Fig. 5		-	3	5.2	A
V _{FR}	forward recovery voltage	I _F = 10 A; dI _F /dt = 10 A/μs; Fig. 6		-	3.2	-	V



- (1) $T_j = 150 \text{ }^\circ\text{C}$; typical values
- (2) $T_j = 150 \text{ }^\circ\text{C}$; maximum values
- (3) $T_j = 25 \text{ }^\circ\text{C}$; maximum values

Fig. 4. Forward current as a function of forward voltage

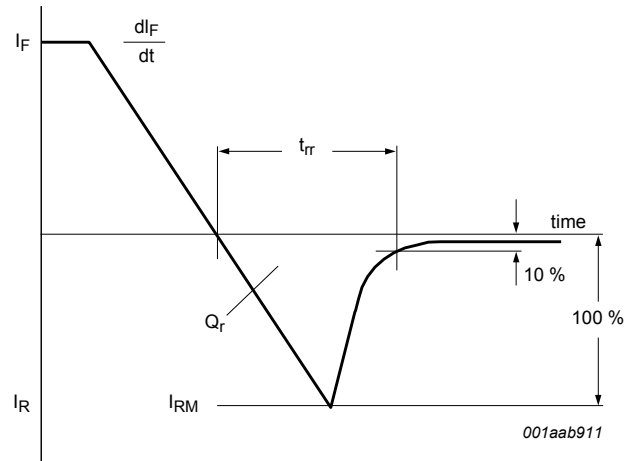


Fig. 5. Forward recovery definitions

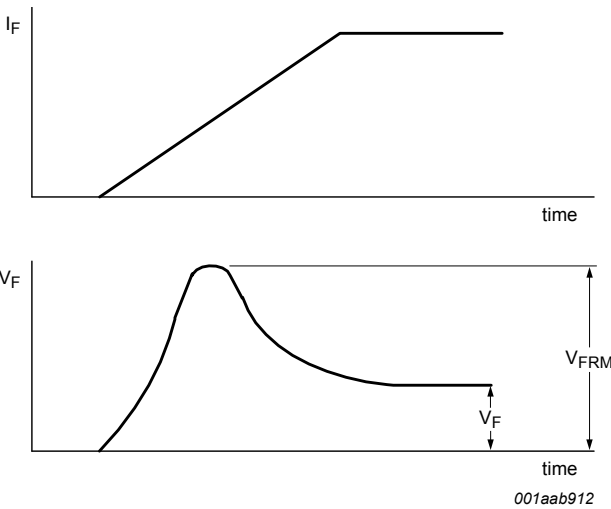


Fig. 6. Forward recovery definitions

11. Package outline

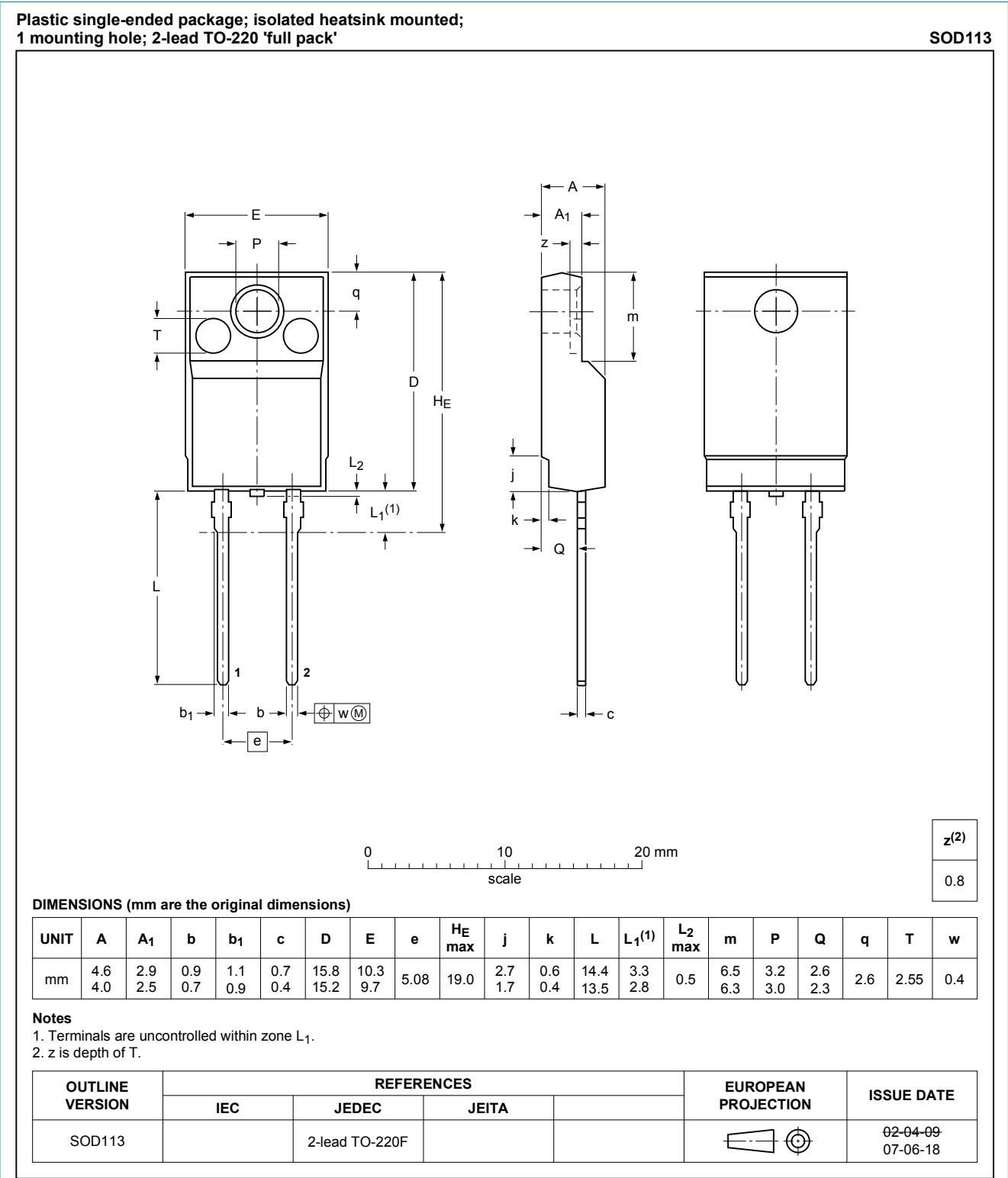


Fig. 7. Package outline TO-220F (SOD113)

12. Legal information

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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